

### Vishay Semiconductors

# **Small Signal Fast Switching Diodes**



#### **FEATURES**

- · Silicon epitaxial planar diode
- Electrically equivalent diodes: 1N4148 - 1N914
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





FREE

#### **APPLICATIONS**

• Extreme fast switches

# **DESIGN SUPPORT TOOLS** click logo to get started



#### **MECHANICAL DATA**

Case: DO-35 (DO-204AH)
Weight: approx. 105 mg
Cathode band color: black
Packaging codes / options:

TR/10K per 13" reel (52 mm tape), 50K/box TAP/10K per ammopack (52 mm tape), 50K/box

| PARTS TABLE |                        |              |                       |                          |  |  |
|-------------|------------------------|--------------|-----------------------|--------------------------|--|--|
| PART        | ORDERING CODE          | TYPE MARKING | CIRCUIT CONFIGURATION | REMARKS                  |  |  |
| 1N4148      | 1N4148-TAP or 1N4148TR | V4148        | Single                | Tape and reel / ammopack |  |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                  |                    |       |      |  |
|--|----------------------------------|--------------------|-------|------|--|
| PARAMETER  | TEST CONDITION                   | SYMBOL             | VALUE | UNIT |  |
| Repetitive peak reverse voltage  |                                  | $V_{RRM}$          | 100   | V    |  |
| Reverse voltage  |                                  | V <sub>R</sub>     | 75    | V    |  |
| Peak forward surge current   | t <sub>p</sub> = 1 μs            | I <sub>FSM</sub>   | 2     | Α    |  |
| Repetitive peak forward current  |                                  | I <sub>FRM</sub>   | 500   | mA   |  |
| Forward continuous current   |                                  | I <sub>F</sub>     | 300   | mA   |  |
| Average forward current  | V <sub>R</sub> = 0               | I <sub>F(AV)</sub> | 150   | mA   |  |
| Dawer dissination  | I = 4 mm, T <sub>L</sub> = 45 °C | P <sub>tot</sub>   | 440   | mW   |  |
| Power dissipation  | I = 4 mm, T <sub>L</sub> ≤ 25 °C | P <sub>tot</sub>   | 500   | mW   |  |

| THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                     |                   |             |      |  |
|--|-------------------------------------|-------------------|-------------|------|--|
| PARAMETER  | TEST CONDITION                      | SYMBOL            | VALUE       | UNIT |  |
| Thermal resistance junction to ambient air                                     | I = 4 mm, T <sub>L</sub> = constant | R <sub>thJA</sub> | 350         | K/W  |  |
| Junction temperature   |                                     | Tj                | 175         | °C   |  |
| Storage temperature range  |                                     | T <sub>stg</sub>  | -65 to +150 | °C   |  |



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |      |      |      |      |
|--|---|-------------------|------|------|------|------|
| PARAMETER  | TEST CONDITION  | SYMBOL            | MIN. | TYP. | MAX. | UNIT |
| Forward voltage  | I <sub>F</sub> = 10 mA  | V <sub>F</sub>    |      |      | 1    | V    |
|  | V <sub>R</sub> = 20 V   | I <sub>R</sub>    |      |      | 25   | nA   |
| Reverse current  | V <sub>R</sub> = 20 V, T <sub>j</sub> = 150 °C  | I <sub>R</sub>    |      |      | 50   | μA   |
|  | V <sub>R</sub> = 75 V   | I <sub>R</sub>    |      |      | 5    | μA   |
| Breakdown voltage  | $I_R = 100 \mu A, t_p/T = 0.01,$<br>$t_p = 0.3 \text{ ms}$                                | V <sub>(BR)</sub> | 100  |      |      | V    |
| Diode capacitance  | $V_R = 0 \text{ V, f} = 1 \text{ MHz,}$<br>$V_{HF} = 50 \text{ mV}$                       | C <sub>D</sub>    |      |      | 4    | pF   |
| Rectification efficiency   | V <sub>HF</sub> = 2 V, f = 100 MHz  | η <sub>r</sub>    | 45   |      |      | %    |
| Reverse recovery time  | $I_F = I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}$   | t <sub>rr</sub>   |      |      | 8    | ns   |
| neverse recovery time  | $I_F = 10 \text{ mA}, V_R = 6 \text{ V},$<br>$I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$ | t <sub>rr</sub>   |      |      | 4    | ns   |

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

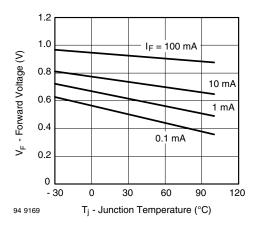


Fig. 1 - Forward Voltage vs. Junction Temperature

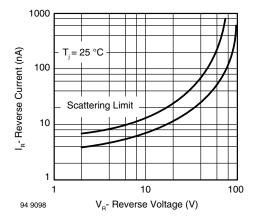


Fig. 3 - Reverse Current vs. Reverse Voltage

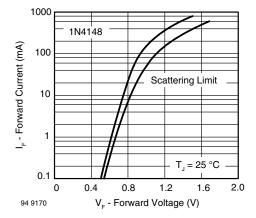
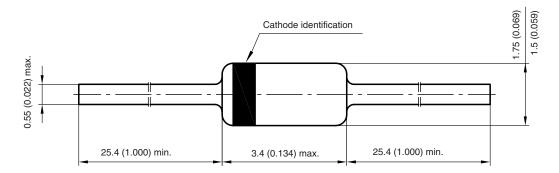


Fig. 2 - Forward Current vs. Forward Voltage



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### PACKAGE DIMENSIONS in millimeters (inches): DO-35 (DO-204AH)



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